

C-MOS QUAD SPST ANALOG SWITCH

■ GENERAL DESCRIPTION

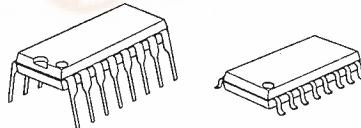
The NJU201A is a quad break-before-make SPST analog switch protected up to 44V operating voltage.

All switches are controlled by TTL or C-MOS compatible input.

The low on-state resistance is about half compare with the NJU7301.

The NJU201A is functionally and pin-to-pin compatible with SILICONIX DG201A.

■ PACKAGE OUTLINE



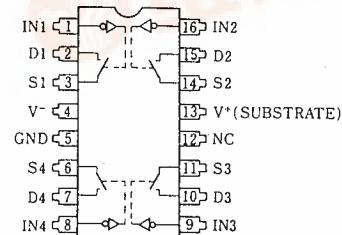
NJU201AD

NJU201AM

■ FEATURES

- High Break Down Voltage -- 44V
- Low On-state Resistance
- Package Outline -- DIP/DMP 16
- C-MOS Technology

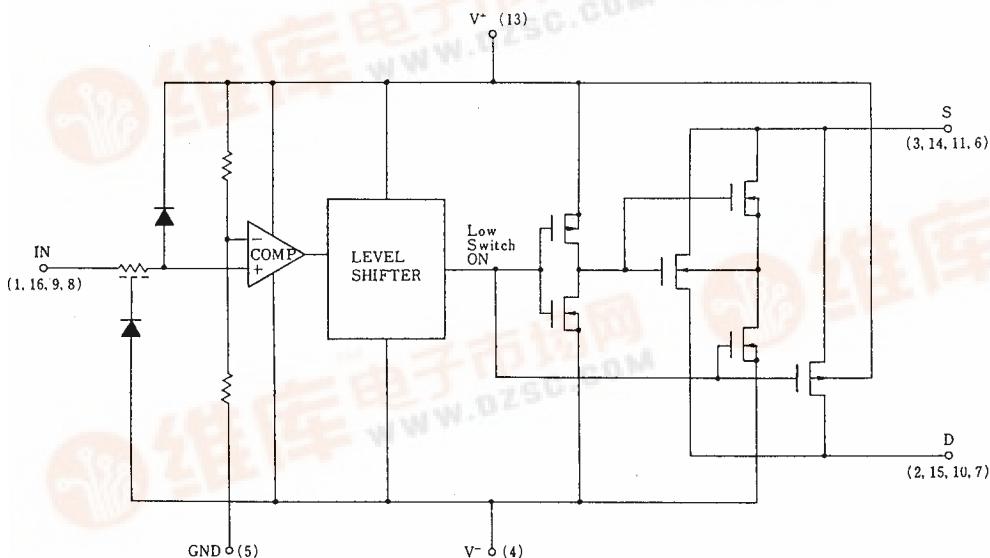
■ PIN CONFIGURATION


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■ TRUTH TABLE

Logic (In)	Switch
0	ON
1	OFF

■ EQUIVALENT CIRCUIT



* Logic input threshold voltage V_{TH} is about $V^+ \times 0.128(V)$.
When the designing, enough margin is required.

■ TERMINAL DESCRIPTION

No.	SYMBOL	FUNCTION	No.	SYMBOL	FUNCTION
1	IN1	Control Signal Input	9	IN3	Control Signal Input
2	D1	Input/Output 1	10	D3	Input/Output 3
3	S1		11	S3	
4	V ⁻	Negative (V ⁻) Power Supply	12	NC	Non Connection
5	GND	Ground	13	V ⁺	Positive (V ⁺) Power Supply
6	S4	Input/Output 4	14	S2	Input/Output 2
7	D4		15	D2	
8	IN4	Control Signal Input	16	IN2	Control Signal Input

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■ ABSOLUTE MAXIMUM RATINGS

(Ta=25°C)

P A R A M E T E R	S Y M B O L	R A T I N G S	U N I T
Supply Voltage	V ⁺ - V ⁻	44	V
	V ⁺ - GND	19	
	GND - V ⁻	25	
Input Voltage	V _I , V _S , V _D	V -0.5 ~ V ⁺ +0.5 *	V
Input Current	I _I	30	mA
	I _S , I _D Continuous	20	
	Peak Value (PW=1ms, Duty0.1)	70	
Power Dissipation	P _D	500 (DIP) / 200 (DMP)	mW
Operating Temperature Range	T _{opr}	0 ~ + 70	°C
Storage Temperature Range	T _{stg}	- 65 ~ + 125	°C

* V⁺+0.5V must be 44V or less.

■ ELECTRICAL CHARACTERISTICS (DC CHARACTERISTICS)

(V⁺=15V, V⁻=-15V, GND=0V)

PARAMETER	SYMBOL	CONDITIONS	TYP	MAX			UNIT
			25°C	0°C	25°C	70°C	
Analog Signal Range	V _{ANALOG}		±15		±15	±15	V
On-state Resistance	R _{ON}	V _{iN} =0.8V	50	100	100	125	Ω
		I _s =-1mA	50	100	100	125	
Source-off Leakage Current	I _s (off)	V _i =2.4V	0.01		5	100	nA
		V _s =14V, V _D =-14V	-0.02		-5	-100	
Drain-off Leakage Current	I _D (off)	V _i =2.4V	0.01		5	100	nA
		V _D =-14V, V _s =14V	-0.02		-5	-100	
Drain-on Leakage Current	I _D (on)	V _i =0.8V	0.1		5	200	nA
		V _D =V _s =-14V	-0.15		-5	-200	
Input Current	I _{TH}	V _i =2.4V	-0.0004		-1	-10	μA
		V _i =15V	0.003		1	10	
Quiescent Current	I ⁺	V _i =0 or 2.4V	0.9		2		mA
	I ⁻		-0.3		-1		

■ SWITCHING CHARACTERISTICS

(V⁺=15V, V⁻=-15V, GND=0V)

PARAMETER	SYMBOL	CONDITIONS	TYP	MAX			UNIT
			25°C	0°C	25°C	70°C	
Turn-on Time	t _{on}	R _L =1kΩ, C _L =35pF	480		600		ns
Turn-off Time	t _{off}		370		450		
Charge Injection	Q	C _L =1000pF, V _{GEN} =0V, R _{GEN} =0Ω	20				pC
Source-Off Capacit.	C _S (off)		5				
Drain-Off Capacit.	C _D (off)	f=100kHz	5				pF
Channel-On Capacitance	C _D (on) +C _S (on)		16				
Off Isolation	OIRR	V _S =2V _{P-P} , f=100kHz, R _L =75Ω	70				dB
Channel-to-channel Crosstalk	CCRR		90				

NJU201A

MEMO

[CAUTION]
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